

AUTOMOTIVE GRADE

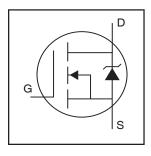


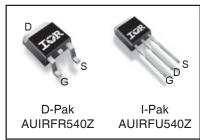
V _{DSS}	100V
R _{DS(on)} typ.	22.5m $Ω$
max.	28.5m $Ω$
I _D	35A

Applications

- Automatic Voltage Regulator (AVR)
- Solenoid Injection
- **Body Control**
- Low Power Automotive Applications

HEXFET® Power MOSFET





G	D	S
Gate	Drain	Source

Base next number	Deelsege Type	Standard Pack	Oudership Doub Normhou	
Base part number	Package Type	Form Quar		Orderable Part Number
		Tube	75	AUIRFR540Z
AUIRFR540Z	Dpak	Tape and Reel	2000	AUIRFR540ZTR
AUINFN340Z		Tape and Reel Left	3000	AUIRFR540ZTRL
		Tape and Reel Right	3000	AUIRFR540ZTRR
AUIRFU540Z	IPak	Tube	75	AUIRFU540Z

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
$I_D @ T_C = 25^{\circ}C$	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	35	
$I_D @ T_C = 100^{\circ}C$	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	25	Α
I _{DM}	Pulsed Drain Current ①	140	
$P_D @ T_C = 25^{\circ}C$	Power Dissipation	91	W
	Linear Derating Factor	0.61	W/°C
V_{GS}	Gate-to-Source Voltage	± 20	V
E _{AS}	Single Pulse Avalanche Energy (Thermally Limited) ②	39	mJ
E _{AS (tested)}	Single Pulse Avalanche Energy Tested Value ®	75	
I _{AR}	Avalanche Current ①	See Fig.12a, 12b, 15, 16	Α
E _{AR}	Repetitive Avalanche Energy ®		mJ
TJ	Operating Junction and	-55 to + 175	
T _{STG}	Storage Temperature Range		°C
	Reflow Soldering Temperature, for 10 seconds	300	

Thermal Resistance

	Parameter	Тур.	Max.	Units	
$R_{\theta JC}$	Junction-to-Case ®		1.64		
$R_{\theta JA}$	Junction-to-Ambient (PCB mount) ② ®		40	°C/W	
$R_{\theta JA}$	Junction-to-Ambient ®		110		

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^{*}Qualification standards can be found at http://www.irf.com/



Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	100			V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient		0.092		V/°C	Reference to 25°C, I _D = 1mA
R _{DS(on)}	Static Drain-to-Source On-Resistance		22.5	28.5	mΩ	V _{GS} = 10V, I _D = 21A ③
V _{GS(th)}	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}$, $I_D = 50\mu A$
gfs	Forward Transconductance	28			S	$V_{DS} = 25V, I_D = 21A$
I _{DSS}	Drain-to-Source Leakage Current			20	μΑ	$V_{DS} = 100V, V_{GS} = 0V$
				250		$V_{DS} = 100V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			200	nA	$V_{GS} = 20V$
	Gate-to-Source Reverse Leakage	_		-200		V _{GS} = -20V
Q_{g}	Total Gate Charge		39	59		I _D = 21A
Q_{gs}	Gate-to-Source Charge		11		nC	$V_{DS} = 50V$
Q_{gd}	Gate-to-Drain ("Miller") Charge	_	12			V _{GS} = 10V ③
t _{d(on)}	Turn-On Delay Time	_	14			$V_{DD} = 50V$
t _r	Rise Time	_	42			I _D = 21A
t _{d(off)}	Turn-Off Delay Time		43		ns	$R_G = 13 \Omega$
t _f	Fall Time		34			V _{GS} = 10V ③
L _D	Internal Drain Inductance		4.5			Between lead,
					nH	6mm (0.25in.)
L _S	Internal Source Inductance		7.5			from package
						and center of die contact
C _{iss}	Input Capacitance		1690			$V_{GS} = 0V$
Coss	Output Capacitance		180			$V_{DS} = 25V$
C _{rss}	Reverse Transfer Capacitance		100		pF	f = 1.0 MHz
C _{oss}	Output Capacitance		720		<u> </u>	$V_{GS} = 0V, V_{DS} = 1.0V, f = 1.0MHz$
C _{oss}	Output Capacitance		110		<u> </u>	$V_{GS} = 0V, V_{DS} = 80V, f = 1.0MHz$
C _{oss} eff.	Effective Output Capacitance		190			$V_{GS} = 0V, V_{DS} = 0V \text{ to } 80V $

Source-Drain Ratings and Characteristics

	Parameter	Min.	Тур.	Max.	Units	Conditions
I _S	Continuous Source Current (Body Diode)			35	Α	MOSFET symbol showing the
I _{SM}	Pulsed Source Current (Body Diode) ①			140		integral reverse p-n junction diode.
V _{SD}	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C, I_S = 21A, V_{GS} = 0V$ ③
t _{rr}	Reverse Recovery Time		32	48	ns	$T_J = 25^{\circ}C$, $I_F = 21A$, $V_{DD} = 50V$
Q _{rr}	Reverse Recovery Charge		40	60	nC	di/dt = 100A/µs ③
t _{on}	Forward Turn-On Time	Intrinsic	turn-on t	ime is ne	egligible (turn-on is dominated by LS+LD)

Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11).
- ② Limited by T_{Jmax} , starting $T_J = 25^{\circ}C$, L = 0.17mH R_{G} = 25 $\!\Omega,\,I_{AS}$ = 21 A, V_{GS} =10 V. Part not recommended for use above this value.
- ③ Pulse width \leq 1.0ms; duty cycle \leq 2%.

- $\ensuremath{\mathfrak{G}}$ $\ensuremath{\text{C}}_{\text{oss}}$ eff. is a fixed capacitance that gives the same charging time as $C_{\text{oss}}\,\text{while}\,\,V_{\text{DS}}\,\text{is rising from 0 to 80\%}\,\,V_{\text{DSS}}$.
- $\ \ \, \ \,$ Limited by T_{Jmax} , see Fig.12a, 12b, 15, 16 for typical repetitive avalanche performance.
- © This value determined from sample failure population. 100% tested to this value in production.
- ⑦ When mounted on 1" square PCB (FR-4 or G-10 Material).

Submit Datasheet Feedback



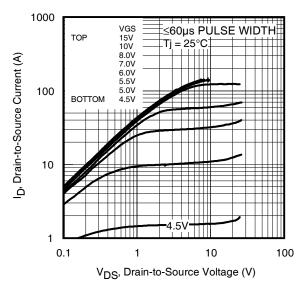


Fig 1. Typical Output Characteristics

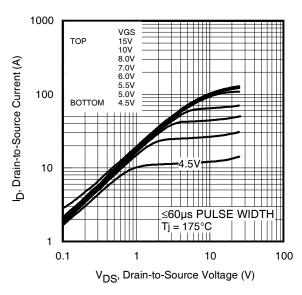


Fig 2. Typical Output Characteristics

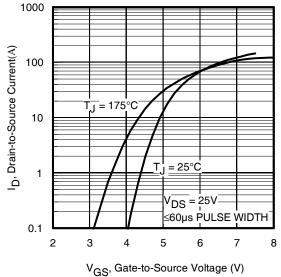


Fig 3. Typical Transfer Characteristics

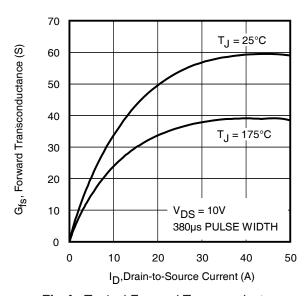


Fig 4. Typical Forward Transconductance vs. Drain Current



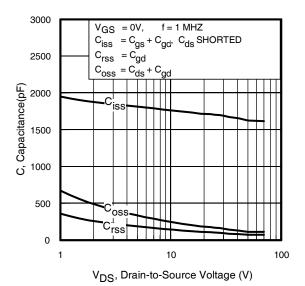


Fig 5. Typical Capacitance vs. Drain-to-Source Voltage

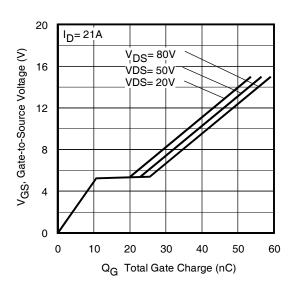


Fig 6. Typical Gate Charge vs. Gate-to-Source Voltage

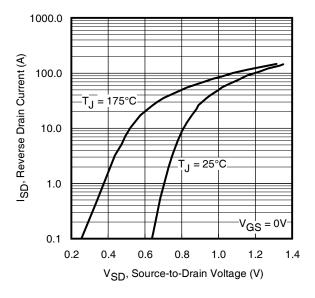


Fig 7. Typical Source-Drain Diode Forward Voltage

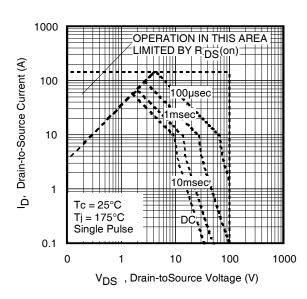


Fig 8. Maximum Safe Operating Area



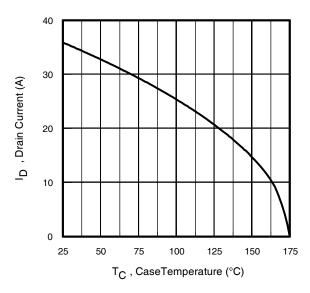


Fig 9. Maximum Drain Current vs. Case Temperature

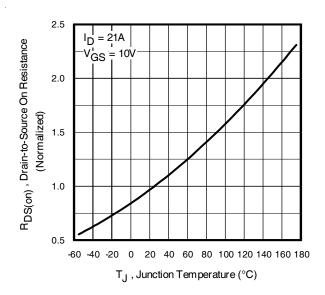


Fig 10. Normalized On-Resistance vs. Temperature

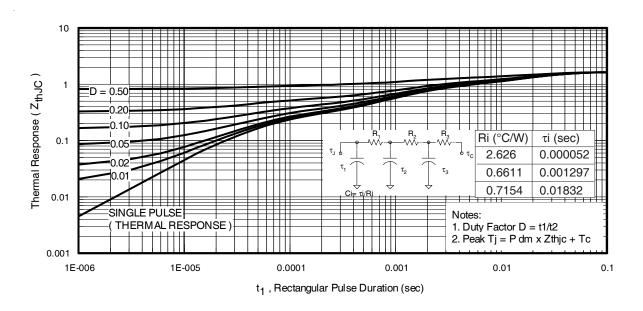


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case



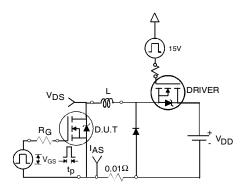


Fig 12a. Unclamped Inductive Test Circuit

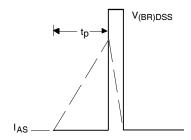


Fig 12b. Unclamped Inductive Waveforms

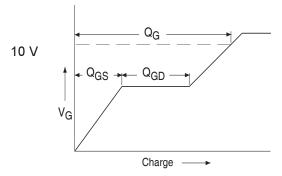
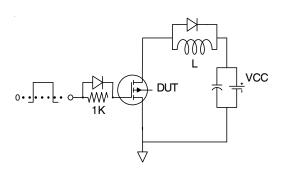


Fig 13a. Basic Gate Charge Waveform



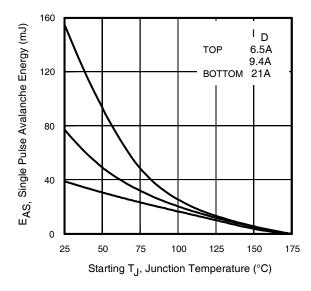


Fig 12c. Maximum Avalanche Energy vs. Drain Current

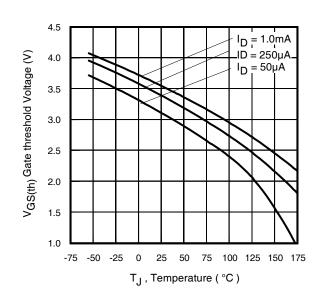


Fig 14. Threshold Voltage vs. Temperature



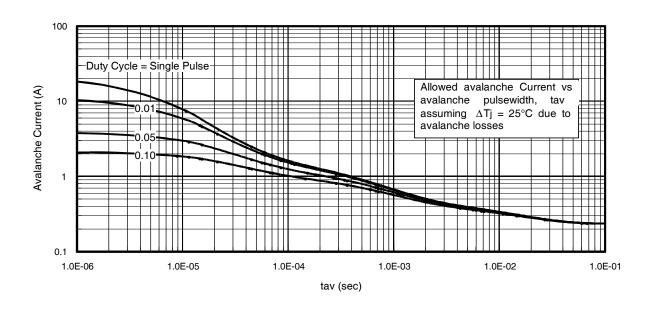


Fig 15. Typical Avalanche Current vs. Pulsewidth

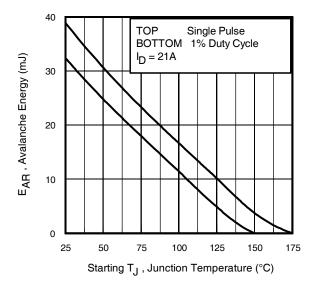


Fig 16. Maximum Avalanche Energy vs. Temperature

Notes on Repetitive Avalanche Curves, Figures 15, 16: (For further info, see AN-1005 at www.irf.com)

- Avalanche failures assumption:
 Purely a thermal phenomenon and failure occurs at a temperature far in excess of T_{jmax}. This is validated for every part type.
- 2. Safe operation in Avalanche is allowed as long $asT_{jmax}\, is$ not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 12a, 12b.
- P_{D (ave)} = Average power dissipation per single avalanche pulse.
- 5. BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. I_{av} = Allowable avalanche current.
- 7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 15, 16). t_{av} = Average time in avalanche. D = Duty cycle in avalanche = t_{av} ·f $Z_{th,JC}(D, t_{av})$ = Transient thermal resistance, see figure 11)

$$\begin{split} P_{D \; (ave)} &= 1/2 \; (\; 1.3 \cdot \text{BV} \cdot \text{I}_{av}) = \triangle \text{T} / \, \text{Z}_{thJC} \\ \text{I}_{av} &= 2 \triangle \text{T} / \; [1.3 \cdot \text{BV} \cdot \text{Z}_{th}] \\ \text{E}_{AS \; (AR)} &= P_{D \; (ave)} \cdot t_{av} \end{split}$$



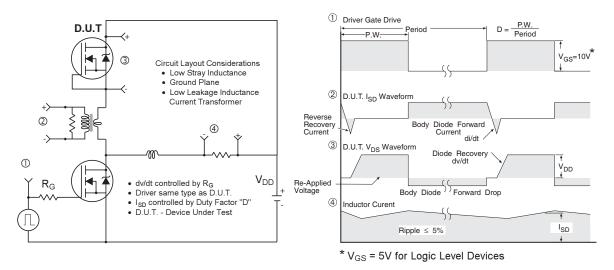


Fig 17. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs

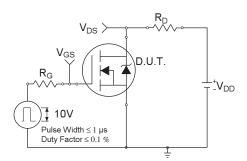


Fig 18a. Switching Time Test Circuit

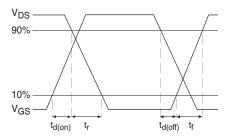
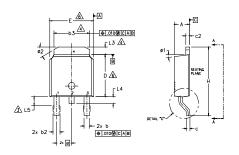


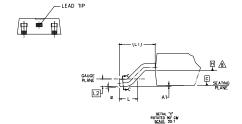
Fig 18b. Switching Time Waveforms

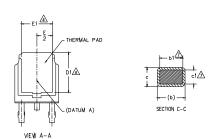


D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)







- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- ⚠ LEAD DIMENSION UNCONTROLLED IN L5.
- ⚠ DIMENSION D1, E1, L3 & b3 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.
- 5.- SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- A- DIMENSION 61 & c1 APPLIED TO BASE METAL ONLY.
- ⚠ DATUM A & B TO BE DETERMINED AT DATUM PLANE H
- 9.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-252AA.

S Y M		Ŋ				
B	MILLIM	ETERS	INC	INCHES		
L	MIN.	MAX.	MIN.	MAX.	N O T E S	
Α	2.18	2,39	.086	.094		
A1	-	0.13	-	.005		
b	0,64	0,89	.025	.035		
ь1	0,65	0.79	.025	.031	7	
ь2	0.76	1,14	.030	.045		
b3	4,95	5,46	.195	.215	4	
С	0.46	0.61	.018	.024		
c1	0.41	0.56	.016	.022	7	
c2	0.46	0.89	.018	.035		
D	5,97	6,22	.235	.245	6	
D1	5.21	-	.205	-	4	
E	6,35	6,73	.250	.265	6	
E1	4,32	-	.170	-	4	
e	2.29	BSC	.090	BSC		
н	9,40	10.41	.370	.410		
L	1,40	1,78	.055	.070		
L1	2.74	BSC	.108	REF,		
L2	0.51	BSC	.020	BSC		
L3	0.89	1.27	.035	.050	4	
L4	-	1.02	-	.040		
L5	1,14	1,52	.045	.060	3	
ø	0.	10*	0.	10*		
ø1	0.	15*	0.	15*		
ø2	25*	35*	25*	35*		

LEAD ASSIGNMENTS

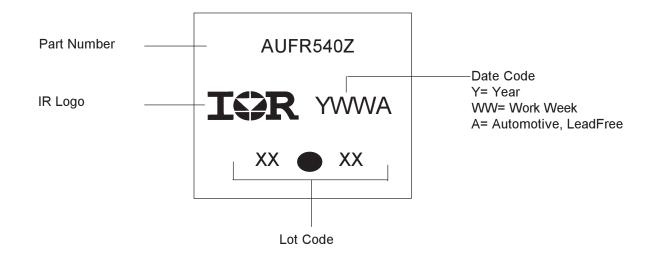
HEXFET

- 1 GATE
- 2.- DRAIN 3.- SOURCE
- 4.- DRAIN

IGBT & CoPAK

- 1,- GATE
 2.- COLLECTOR
 3.- EMITTER
 4.- COLLECTOR

D-Pak Part Marking Information

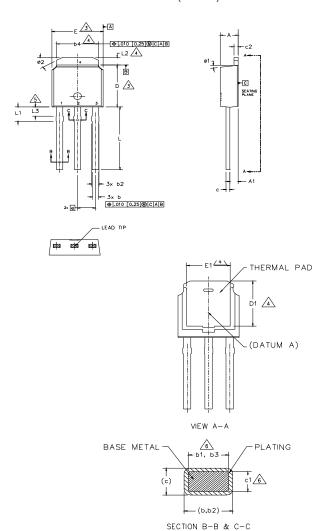


Note: For the most current drawing please refer to IR website at: http://www.irf.com/package/



I-Pak (TO-251AA) Package Outline

Dimensions are shown in millimeters (inches)



NOTES:

- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- THERMAL PAD CONTOUR OPTION WITHIN DIMENSION 64, L2, E1 & D1.
- ⚠ LEAD DIMENSION UNCONTROLLED IN L3.
- DIMENSION 61, 63 & c1 APPLY TO BASE METAL ONLY.
- 7.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-251AA (Date 06/02).
- 8.- CONTROLLING DIMENSION : INCHES,

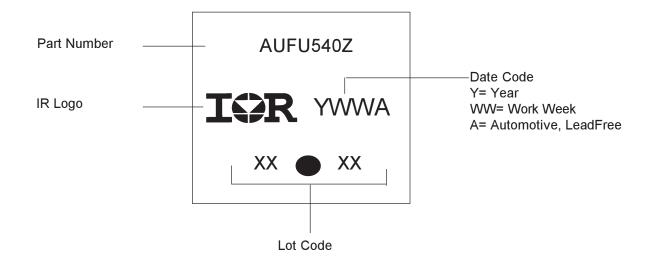
S Y M			Ŋ		
B	MILLIM	ETERS	INCHES		O T E S
B O L	MIN.	MAX.	MIN.	MAX.	S
Α	2.18	2.39	.086	.094	
A1	0.89	1.14	.035	.045	
b	0,64	0.89	.025	.035	
ь1	0.65	0.79	.025	.031	6
b2	0.76	1,14	.030	.045	
b3	0.76	1.04	.030	.041	6
b4	4.95	5.46	.195	.215	4
С	0.46	0.61	.018	.024	
c1	0.41	0.56	.016	.022	6
c2	0.46	0.89	.018	.035	
D	5.97	6.22	.235	.245	3
D1	5,21	-	.205	-	4
Ε	6.35	6.73	.250	.265	3
E1	4.32	_	.170	-	4
e	2.29	BSC	.090	BSC	
L	8.89	9.65	.350	.380	
L1	1.91	2.29	.045	.090	
L2	0.89	1.27	.035	.050	4
L3	1,14	1.52	.045	.060	5
ø1	0,	15°	0*	15*	
ø2	25"	35*	25 °	35'	

LEAD ASSIGNMENTS

HEXFET

- 1.- GATE
- 2.- DRAIN 3.- SOURCE
- 4.- DRAIN

I-Pak Part Marking Information

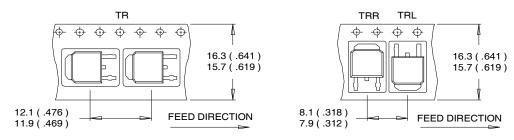


Note: For the most current drawing please refer to IR website at: http://www.irf.com/package/



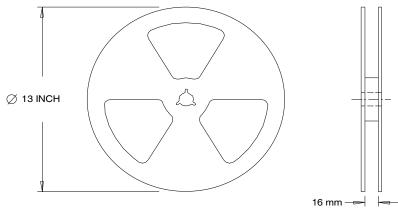
D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



NOTES:

- 1. CONTROLLING DIMENSION : MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



NOTES:

1. OUTLINE CONFORMS TO EIA-481.

Note: For the most current drawing please refer to IR website at: http://www.irf.com/package/

Qualification Information[†]

Qualific	auon imormation				
			Automotive		
		(per AEC-Q101) [†]			
Qualifica	ition Level	Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.			
		D-PAK	MSL1		
worsture	Sensitivity Level	I-PAK	MSL1		
	Machine Model	Class M2 (+/- 200V) ^{††}			
			AEC-Q101-002		
505	Human Body Model		Class H1B (+/- 1000V) ^{††}		
ESD		AEC-Q101-001			
	Charged Device Model	del Class C5 (+/- 2000V) ^{††}			
			AEC-Q101-005		
RoHS Co	mpliant	Yes			

- † Qualification standards can be found at International Rectifier's web site: http://www.irf.com/
- †† Highest passing voltage.



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IR products are neither designed nor intended for use in automotive applications or environments unless the specific IR products are designated by IR as compliant with ISO/TS 16949 requirements and bear a part number including the designation "AU". Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, IR will not be responsible for any failure to meet such requirements.

For technical support, please contact IR's Technical Assistance Center

http://www.irf.com/technical-info/

WORLD HEADQUARTERS:

101 N. Sepulveda Blvd., El Segundo, California 90245

Tel: (310) 252-7105



Revision History

Date	Comments	
6/6/2014	Updated part number by the pictures of the parts to AU nomenclature on page 1.	